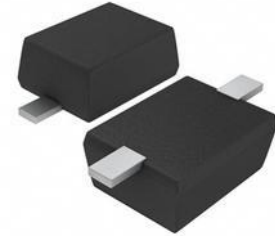
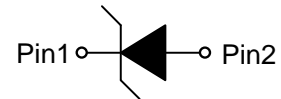


ESD5621WXX
1-Line, Uni-directional, Transient Voltage Suppressor
<http://www.sh-willsemi.com>
Descriptions

The ESD5621WXX is a uni-directional TVS (Transient Voltage Suppressor). It is specifically designed to protect sensitive electronic components which are connected to power lines, from over-stress caused by ESD (Electrostatic Discharge), EFT (Electrical Fast Transients) and Lightning.

The ESD5621WXX may be used to provide ESD protection up to $\pm 30\text{kV}$ (contact and air discharge) according to IEC61000-4-2, and with high surge capability used to protect USB voltage bus pin ($8/20\mu\text{s}$) according to IEC61000-4-5.

The ESD5621WXX is available in SOD-323F package. Standard products are Pb-free and Halogen-free.


SOD-323F (Bottom View)

Circuit diagram
Features

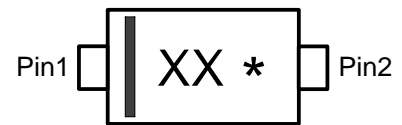
- Reverse stand-off voltage: 4.5V ~ 15V
- Surge protection according to IEC61000-4-5 see [Table 4](#)
- ESD protection according to IEC61000-4-2 $\pm 30\text{kV}$ (contact and air discharge)
- Low clamping voltage
- Solid-state silicon technology

Applications

- Power supply protection
- Power management

Order information
Table 1.

Device	Package	Shipping	Marking
ESD5621W04-2/TR	SOD-323F	3000/Tape&Reel	TE*
ESD5621W10-2/TR	SOD-323F	3000/Tape&Reel	TJ*
ESD5621W-2/TR	SOD-323F	3000/Tape&Reel	Q*
ESD5621W15-2/TR	SOD-323F	3000/Tape&Reel	TD*



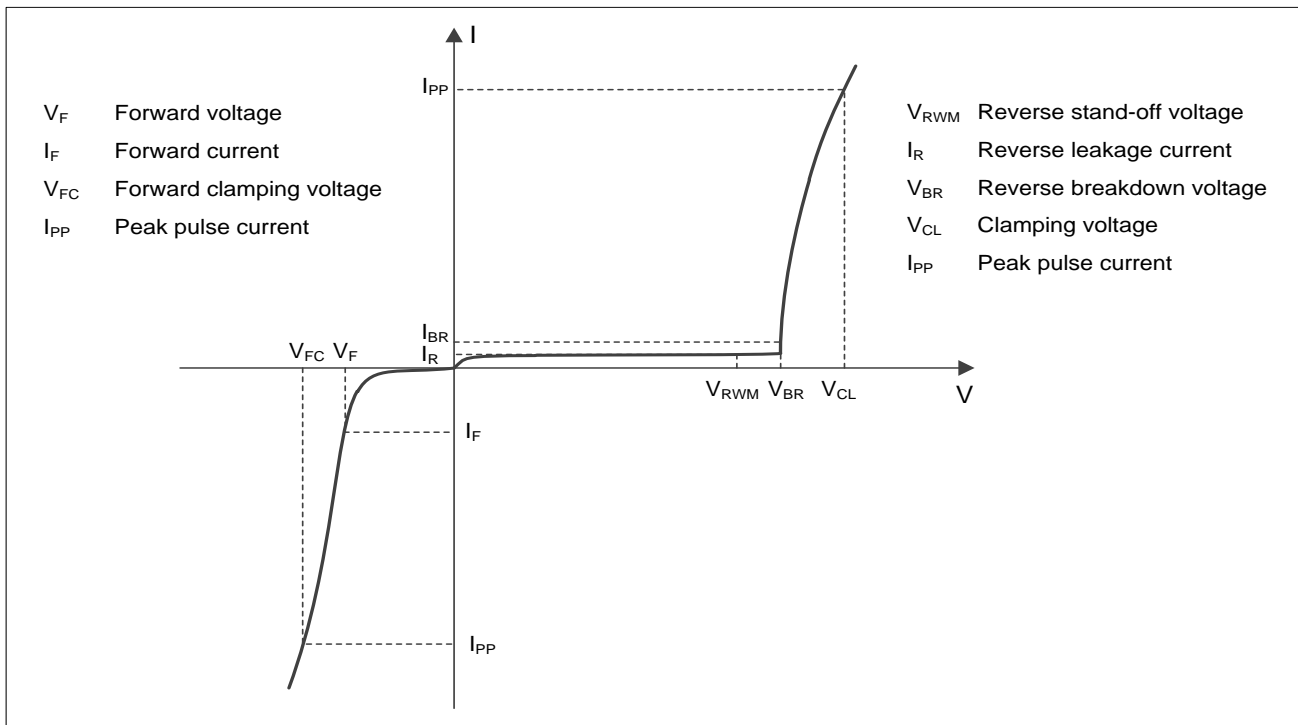
XX = Device code

* = Month code

Marking (Top View)

Absolute maximum ratings
Table 2.

Parameter	Symbol	Rating	Unit
Peak pulse power ($t_p=8/20\mu s$)	Ppk	1400	W
ESD according to IEC61000-4-2 air discharge	V_{ESD}	± 30	kV
ESD according to IEC61000-4-2 contact discharge		± 30	
Junction temperature	T_J	125	$^{\circ}C$
Operating temperature	T_{OP}	-40~85	$^{\circ}C$
Lead temperature	T_L	260	$^{\circ}C$
Storage temperature	T_{STG}	-55~150	$^{\circ}C$

Electrical characteristics ($T_A = 25^{\circ}C$, unless otherwise noted)

Definitions of electrical characteristics

Electrical characteristics ($T_A = 25^\circ\text{C}$, unless otherwise noted)
Table 3.

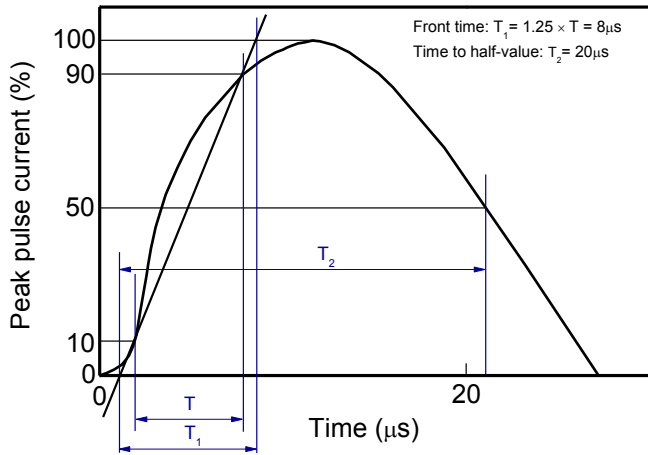
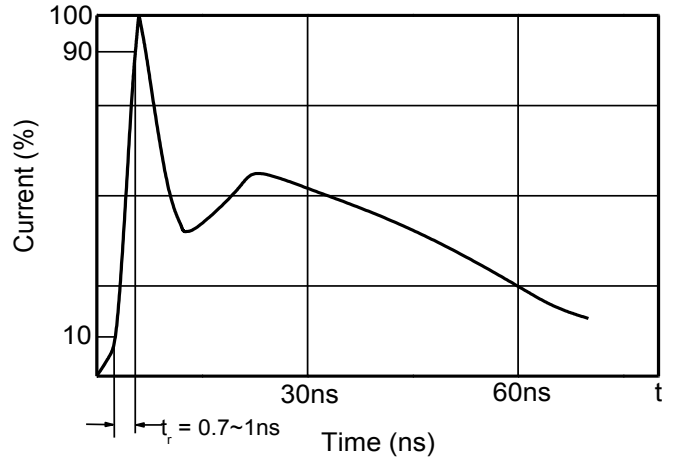
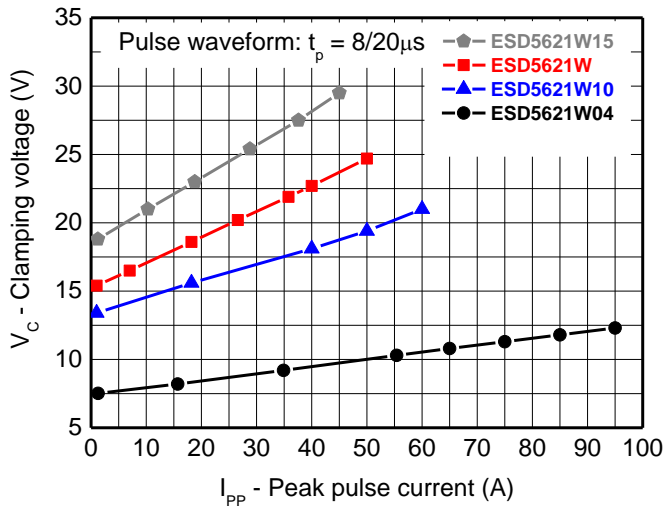
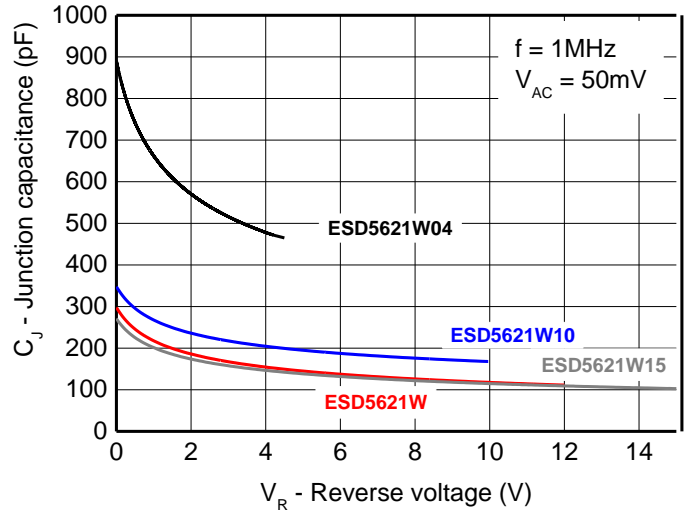
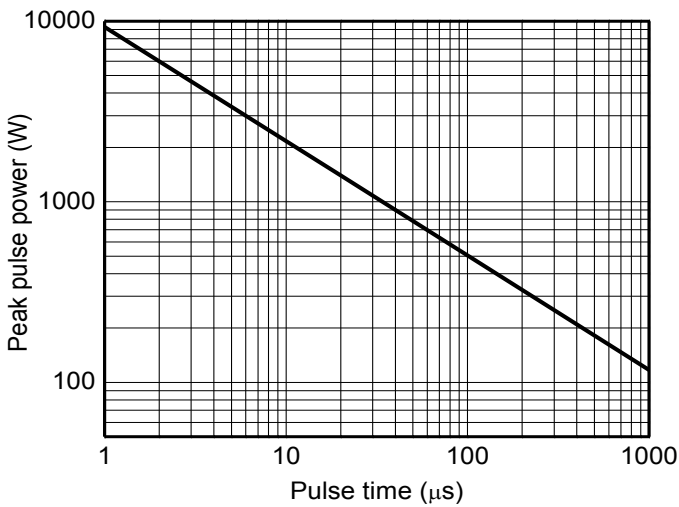
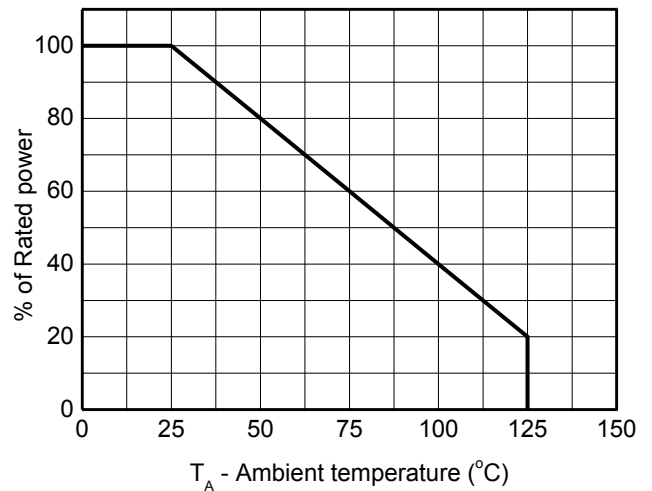
Type number	Reverse Standoff Voltage V_{RWM} (V)	Breakdown voltage V_{BR} (V) $I_{BR} = 1\text{mA}$			Reverse leakage current I_{RM} (μA) at V_{RWM}		Forward voltage V_F (V) $I_F = 20\text{mA}$		Junction capacitance $F = 1\text{MHz}$, $V_R = 0\text{V}$ (pF)	
	Max	Min	Typ	Max	Typ	Max	Min	Max	Typ	Max
ESD5621W04	4.5	5.2	6.1	7.0	-	5.0	0.45	1.25	900	1200
ESD5621W10	10.0	11.5	13.2	15.0		0.1	0.45	1.25	350	500
ESD5621W	12.0	13.0	15.0	17.0	-	0.1	0.45	1.25	300	400
ESD5621W15	15.0	16.0	18.0	20.0	-	0.1	0.45	1.25	270	350

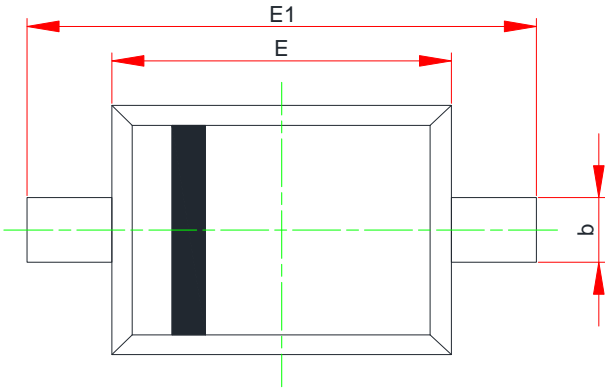
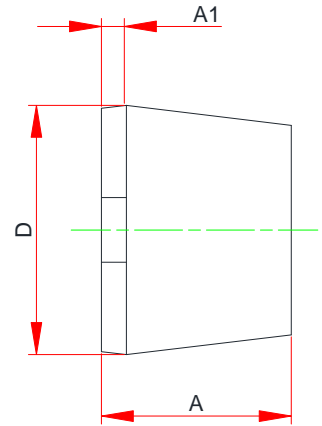
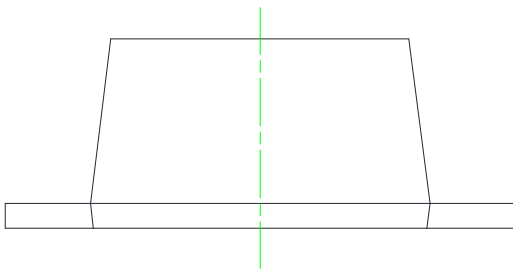
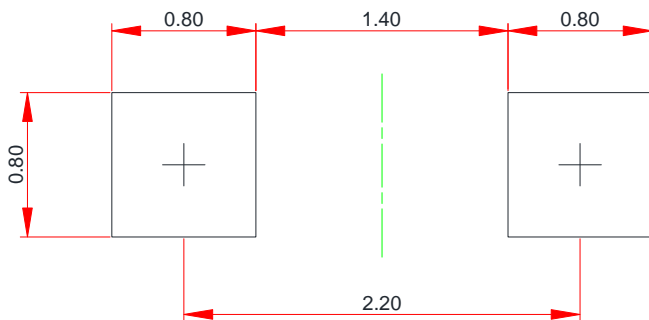
Table 4.

Type number	Rated peak pulse current I_{PP} (A) ¹⁾³⁾	Clamping voltage V_{CL} (V) at I_{PP} (A) ¹⁾³⁾	Clamping voltage V_{CL} (V) at $I_{PP} = 16\text{A}$, $t_p = 100\text{ns}$ ²⁾³⁾	Clamping voltage V_{CL} (V) at $V_{ESD} = 8\text{kV}$ ²⁾³⁾
ESD5621W04	95	14.5	7.0	8.0
ESD5621W10	60	25.0	15.0	16.0
ESD5621W	50	27.5	16.0	17.0
ESD5621W15	45	31.0	20.0	21.0

Notes:

- 1) Non-repetitive current pulse, according to IEC61000-4-5.(8/20 μs current waveform)
- 2) Non-repetitive current pulse, according to IEC61000-4-2.
- 3) Measured from pin 1 to pin 2.

Typical characteristics ($T_A = 25^\circ\text{C}$, unless otherwise noted)

8/20 μs waveform per IEC61000-4-5

Contact discharge current waveform per IEC61000-4-2

Clamping voltage vs. Peak pulse current

Capacitance vs. Reverse voltage

Non-repetitive peak pulse power vs. Pulse time

Power derating vs. Ambient temperature

Package outline dimensions
SOD-323F

Top View

Side View

Side View
Recommend land pattern (Unit: mm)


Symbol	Dimensions in Millimeters		
	Min.	Typ.	Max.
A	0.80	-	1.10
A1	0.10	-	0.15
D	1.15	-	1.35
E	1.60	-	1.80
E1	2.30	-	2.80
b	0.25	-	0.40

Notes:

This recommended land pattern is for reference purposes only. Please consult your manufacturing group to ensure your PCB design guidelines are met.